

Rev. V1P

Features

- Ka-Band Power Amplifier
- Gain: 25 dB
- Output Power: 6 W
- Supply Voltage: 22 V
- PAE: 27%
- Bare Die
- Die Size: 3.275 x 1.75 x 0.1 mm

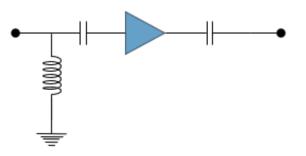
Applications

• Ka-band Satellite Communications

Description

The MAPC-MP0013-DIE is a 6 W, Ka-band power amplifier. This GaN on SiC power amplifier operates at 22 V and has a typical power added efficiency of 27%. Typical applications include Ka-band satellite communications.

Each device is 100% RF tested to ensure performance compliance.



Pin Configuration¹

Functional Schematic

Pin #	Label
1	RF _{IN}
2, 6, 10, 11, 13, 14, 18, 22, 23	GND
3	VG3, VG4
4, 19, 20	NC
5	VD1
7	VD2
8	VD3
9	VD4
12	RF _{OUT}
15	VD4
16	VD3
17	VD2
21	VG1234

1. The backside of the die must be connected to RF, DC and thermal ground.

* Restrictions on Hazardous Substances, compliant to current RoHS EU directive.

Package

Bulk

Sample Board

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Ordering Information

Part Number

MAPC-MP0013-DIEPPR

MAPC-MP0013-SB1PPR



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Pin Description

Pin #	Name	Description	
1	RF_IN	RF Input has DC ground for ESD robustness	
2, 6, 10, 11, 13, 14, 18, 22, 23	GND	RF and DC Ground	
3	VG3, VG4	No connection to circuit, isolated capacitor to ground	
4, 19	NC	No connection to circuit	
5	VD1	Drain voltage, stage 1	
7, 17	VD2	Drain voltage, stage 2	
8, 16	VD3	Drain voltage, stage 3	
9, 15	VD4	Drain voltage, stage 4	
12	RF_OUT	RF Output is DC de-coupled	
20	NC	No connection to circuit, isolated ESD diodes that may be bonded in to protect VG1234	
21	VG1234	Gate voltage, stages 1, 2, 3, and 4	

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Electrical Specifications: Freq. = 27 - 31 GHz, T_c = 25°C, V_D = +22 V, I_{DQ} = 190 mA, CW Operation, Z₀ = 50 Ω

Parameter	Test Conditions	Units	Min.	Тур.	Max.
Gain	Small Signal, P _{IN} = -10 dBm Large Signal, P _{IN} = +21 dBm	dB		25 17	
Gain Flatness (Peak-to-Peak)	() $P_{IN} = -10 \text{ dBm}$ dB —		1	—	
IM3	P _{OUT} = 31 dBm per tone, spacing 100 kHz to 1 GHz	dBc		25	
Output Power	P _{IN} = +21 dBm	dBm	—	38	—
Output Power Flatness	P _{IN} = +21 dBm	dB	_	2	_
Input Return Loss	P _{IN} = -10 dBm	dB	_	8	_
Output Return Loss	P _{IN} = -10 dBm	dB	_	10	_
Power Added Efficiency	P _{IN} = +21 dBm	%	—	27	—

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Recommended Operating Conditions

Parameter	Symbol	Unit	Min.	Тур.	Max.
RF Input Power	RF _{IN}	dBm	—	21	25
Drain Supply Voltage	VD	V	—	22	25
Gate Supply Voltage	VG	V	-5	—	—
Duty Cycle	-	%	—	10	100 (CW)
Junction Temperature ^{4,5}	Tj	°C	—	_	200
Operating Temperature ⁶	T _c	°C	-40	_	85
Storage Temperature	T _s	°C	-55	—	150

Absolute Maximum Ratings^{2,3}

Parameter	Symbol	Unit	Min.	Max.
RF Input Power	RF _{IN}	dBm	_	28
Drain Supply Voltage	VD	V	_	28
Gate Supply Voltage	VG	V	-6	_
Junction Temperature	Tj	°C	_	225
Storage Temperature	Ts	°C	-55	150

2. Exceeding any one or combination of these limits may cause permanent damage to this device.

3. MACOM does not recommend sustained operation near these survivability limits.

4. Operating at nominal conditions with $T_J \le +200$ °C will ensure MTTF > 1 x 10⁶ hours.

5. Junction Temperature $(T_J) = T_C + \Theta jc * (V * I-(P_{OUT}-P_{IN}))$

Typical thermal resistance (Θ jc) = 5.2 °C/W.

a) For T_C = +25°C, Pout = 38 dBm, Pin = 21 dBm:

T_J = 119 °C @ 22 V, 1.1 A

b) For T_C = +85°C, quiescent conditions:

T_J = 179 °C @ 22 V, 1.1 A

6. T_{C} is defined as backside of die.

Handling Procedures

Please observe the following precautions to avoid damage:

Static Sensitivity

These electronic devices are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.

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Application Notes

MAPC-MP0013-DIE is designed to be easy to use yet high performance. The ultra small size and simple bias allows easy placement on system board. RF output ports are DC de-coupled internally. RF input port has DC connection to the ground for the ESD protection purpose.

Die Attachment

This product is manufactured from 0.1 mm (0.004") thick SiC substrate and has vias through to the backside to enable grounding to the circuit.

Recommended conductive epoxy is Namics Unimec XH9890-6. Epoxy should be applied and cured in accordance with the manufacturer's specifications and should avoid contact with the top of the die.

Supply Sequencing Turn-on

- 1. Apply V_G (-5 V).
- 2. Apply V_D (22 V typical).
- 3. Set I_{DQ} by adjusting V_G more positive (typically V_G~ -3.9 V for I_{DQ} = 190 mA).
- Apply RF_{IN} signal.

Turn-off

- 1. Remove RF_{IN} signal.
- 2. Decrease V_G to -5 V.
- 3. Decrease V_D to 0 V.

Biasing Conditions

Recommended biasing conditions are: $V_D = 22 V$, $I_{DQ} = 190 \text{ mA}$ (controlled with V_G).

 V_{D} bias must be applied to $V_{\text{D}}1,~V_{\text{D}}2,~V_{\text{D}}3,$ and $V_{\text{D}}4$ pads.

Both $V_{\text{D}}3$ pads (8, 16) are required for current symmetry.

Both $V_{\text{D}}4$ pads (9, 15) are required for current symmetry.

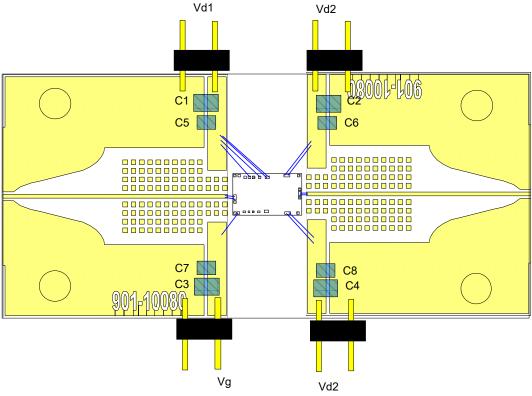
A single DC voltage (V_G) will bias all amplifier stages. Muting can be accomplished by setting the V_G to the pinched off voltage (V_G = -5 V).

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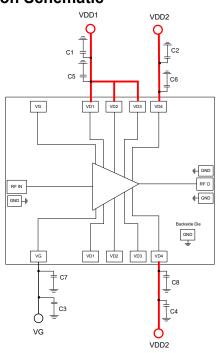


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Sample Board Layout



Application Schematic



Parts List

Part	Value	Case Style
C5 - C8	0.01 µF	0402
C1 - C4	22 µF	0603

Sample Board Material Specifications

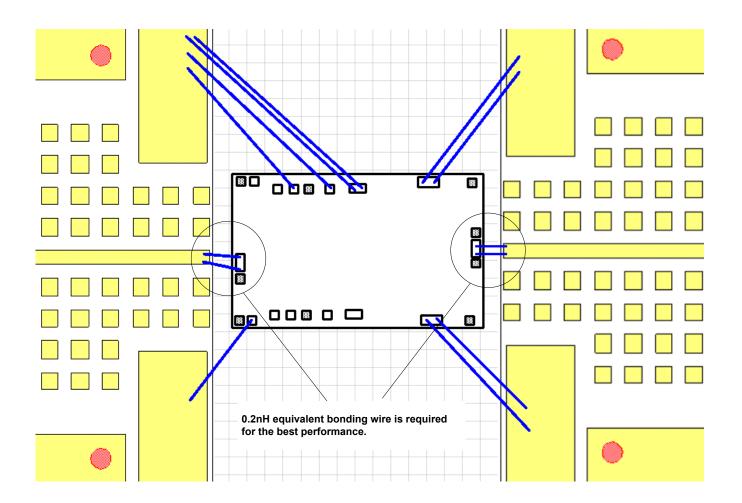
Top Layer: 1/2 oz Copper Cladding, 0.017 mm thickness *Dielectric Layer:* Rogers RO4350B 0.101 mm thickness *Bottom Layer:* 1/2 oz Copper Cladding, 0.017 mm thickness *Finished overall thickness:* 0.135 mm

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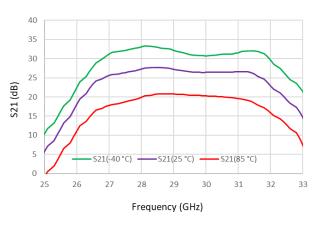
Recommended Bonding Diagram and PCB Layout Detail:

Optimum bonding wire inductance for the RF I/O connection is 0.2 nH, and physical length for the gold bond wire (.001" dia.) is approximately 350 μ m each for the two wire connection.



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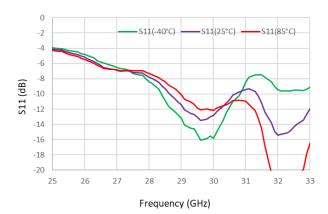




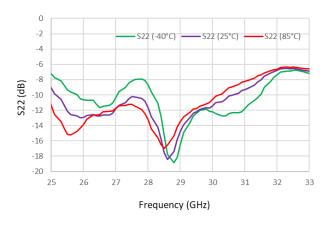
Typical Performance Curves: $V_D = 22 V$, $I_{DSQ} = 190 mA$, $V_G = -3.9 V$ typical

Small Signal Gain vs. Frequency over Temperature

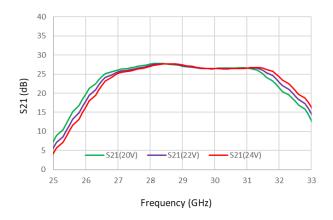
Input Return Loss vs. Frequency over Temperature



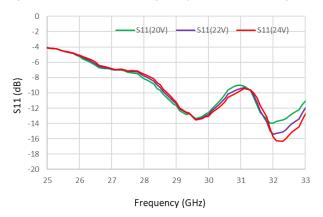
Output Return Loss vs. Frequency over Temperature



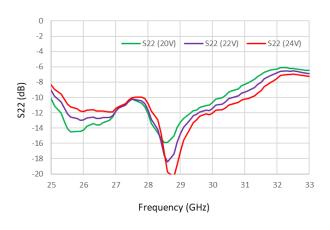
Small Signal Gain vs. Frequency over Bias Voltage



Input Return Loss vs. Frequency over Bias Voltage



Output Return Loss vs. Frequency over Bias Voltage

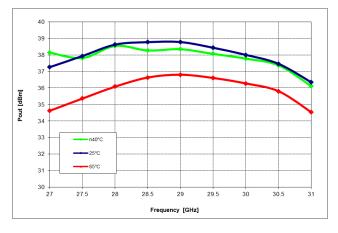


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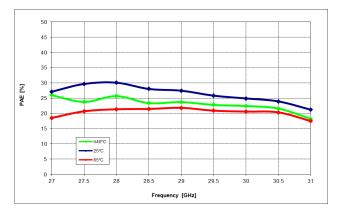


Typical Performance Curves: V_D = 22 V, I_{DSQ} = 190 mA, V_G = -3.9 V typical, Pin = 21 dBm

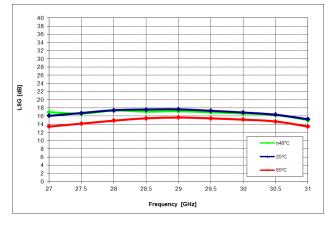
Pout vs. Frequency over Temperature



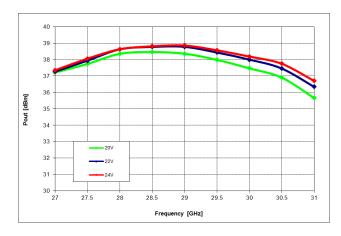
PAE vs. Frequency over Temperature



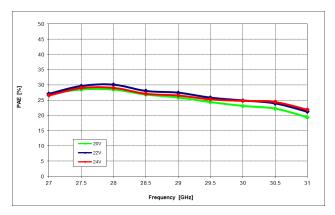
Large Signal Gain vs. Frequency over Temperature



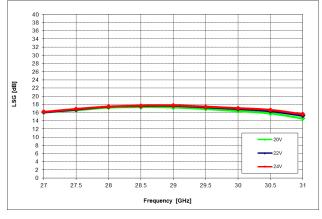
Pout vs. Frequency over Bias Voltage



PAE vs. Frequency over Bias Voltage



Large Signal Gain vs. Frequency over Bias Voltage

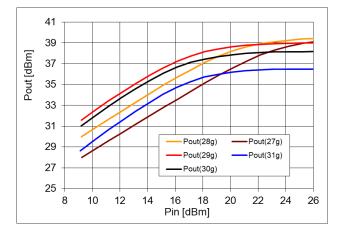


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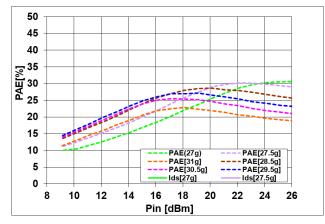


Typical Performance Curves: V_D = 22 V, I_{DSQ} = 190 mA, V_G = -3.9 V typical, 25°C

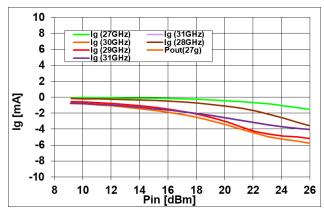
Output Power vs. Input Power at 25°C



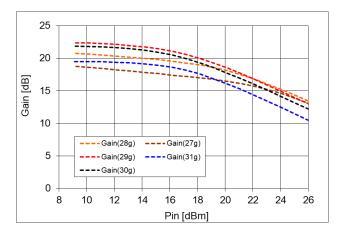
PAE vs. Input Power at 25°C



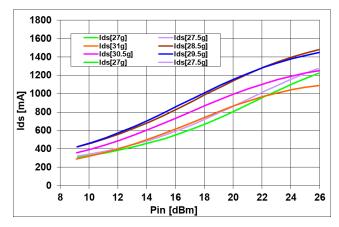
Gate Current vs. Input Power at 25°C



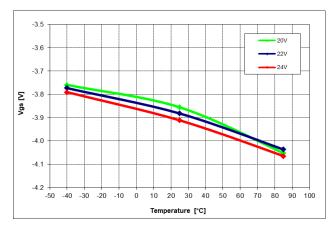
Gain vs. Input Power at 25°C



Drain Current vs. Input Power at 25°C



Gate Voltage vs. Temperature for Constant Idsq

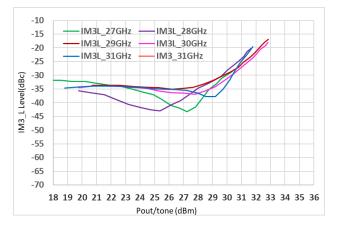


¹⁰

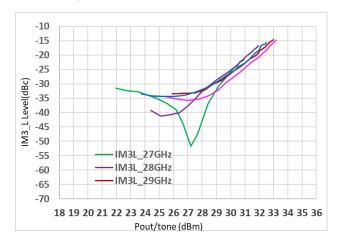


Typical Performance Curves: V_D = 22 V, I_{DSQ} = 190 mA, V_G = -3.9 V typical

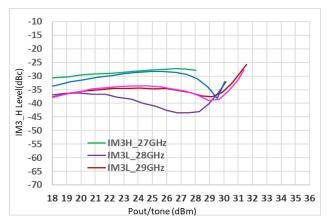
IM3 vs. Output Power (25 °C)



IM3 vs. Output Power (-40 °C)



IM3 vs. Output Power @ 85°C



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MAPC-MP0013-DIE

Rev. V1P

Die Dimensions 3111 Ξ 23 20 19 18 22 21 \square 0, 0 3111

Die thickness is 100 +/- 10 µm.

Revision history

Rev	Date	Change description
V1P	1/31/23	Release of preliminary data sheet



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